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## The Silicides $YT_2Si_2$ (T = Co, Ni, Cu, Ru, Rh, Pd): A Systematic Study by <sup>89</sup>Y Solid State NMR Spectroscopy

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The ThCr<sub>2</sub>Si<sub>2</sub>-type silicides  $YT_2Si_2$  (T = Co, Ni, Cu, Ru, Rh, Pd) were synthesized from the elements by arc-melting. They were characterized by X-ray powder diffraction and the structures were refined on the basis of single-crystal X-ray diffractometer data. The course of the lattice parameters shows a distinct anomaly for YRu<sub>2</sub>Si<sub>2</sub> which shows the by far smallest c/a ratio along with elongated Y–Si distances. Systematic <sup>89</sup>Y solid state NMR spectra are dominated by large Knight shifts arising from unpaired conduction electron spin density near the Fermi edge. The Knight shift decreases with increasing valence electron count (VEC), reflecting the sensitivity of this parameter to electronic properties. The particularly strong structural distortion observed in YRu<sub>2</sub>Si<sub>2</sub> manifests itself in a sizeable magnetic shielding anisotropy. Electronic structure calculations for YRu<sub>2</sub>Si<sub>2</sub> and YRh<sub>2</sub>Si<sub>2</sub> reveal similar projected density of states (PDOS) shapes with an energy upshift of the Fermi level in  $YRh_2Si_2$  due to the extra electron brought in by Rh. As a consequence, the PDOS at the Fermi energy is twice as large in the Ru compound as in the Rh compound. While both compounds show the major bonding interaction within the  $T_2Si_2$  layers,  $YRh_2Si_2$  exhibits significant stronger Y–Si bonding.

Key words: Yttrium, Silicides, Crystal Structure, Solid State NMR Spectroscopy

#### Introduction

The tetragonal BaAl<sub>4</sub> type [1], space group *I*4/*mmm* and its ternary derivative ThCr<sub>2</sub>Si<sub>2</sub> [2] are two of the most frequent structure types that occur for intermetallic compounds. The Pearson data base [3] lists several hundred representatives. The crystallographic details and the widely varying physical properties have been reviewed [4, 5]. The ThCr<sub>2</sub>Si<sub>2</sub> derivatives of the general formula  $AT_2X_2$  exist for many different element combinations. The *A* cations can be an alkali, alkaline earth, rare earth, or actinoid metal and the whole series of transition metals has been observed on the *T* sites. The *X* sites can be occupied by elements of the 3<sup>rd</sup>, 4<sup>th</sup>, and 5<sup>th</sup> main group. This flexibility in the site occupancies allows for variations of the valence electron count (VEC) and thus of the magnetic ground states. Especially the cerium and uranium containing phases have been studied extensively during the past thirty years in the context of heavy fermion systems [6, 7]. The same holds true for the europium and ytterbium compounds, whose electronic properties are characterized by valence fluctuations.

The  $AT_2X_2$  phases show a wide range of c/a ratios [5], resulting from variations in the *A*, *T*, and *X* atomic size ratios. In addition, the lattice parameters also reflect variations in *X*–*X* bonding, depending on whether the *X* atoms are isolated or form covalently bonded  $X_2$  dumb-bells. The simple formula  $d_{X-X} = (0.16 + 0.04(c/a))c$  [8] allows a fast estimation of the *X*–*X* distance. These bonding peculiarities have been intensively studied by electronic structure calculations [9-11] with pioneering work by done the Hoffmann group.

Several of the  $AT_2X_2$  phases show superconductivity at very low temperatures. Early work on YPt<sub>2</sub>Si<sub>2</sub> [12], YIr<sub>2</sub>Si<sub>2</sub> [13], YPd<sub>2</sub>Si<sub>2</sub>, and YRh<sub>2</sub>Si<sub>2</sub> [14] revealed transition

temperatures below 3 K. This field of research gained a true renaissance shortly after the discovery of superconductivity in the solid solution  $Ba_{1-x}K_xFe_2As_2$  [15, 16] with  $T_{max} = 38$  K. The huge field on superconductivity and charge density work on  $AT_2X_2$ phases has been reviewed by Johnston [17].

For developing an understanding of electronic properties in terms of atomic composition and structure in intermetallic compounds, solid state NMR spectroscopy is a useful tool, as the Knight shifts available from such measurements reflect unpaired conduction electron spin densities near the Fermi edge. Recently, we have been exploring the potential of the <sup>89</sup>Y nucleus to reveal such information for intermetallic compounds [18]. The isoypical series  $YT_2X_2$  with its wide range of lattice parameters and electronic properties is an attractive candidate in this context. Herein we report on detailed crystallographic and <sup>89</sup>Y NMR spectroscopic trends observed for the silicides  $YT_2Si_2$  with T = Co, Ni, Cu, Ru, Rh, Pd. These yttrium silicides were studied previously during investigations of the complete *RET*<sub>2</sub>Si<sub>2</sub> series in order to manifest the non-magnetic ground states of the [ $T_2Si_2$ ] networks (Table 1 [12-14, 19-31]).

#### Experimental

#### *Synthesis*

The starting materials for the preparation of the series of  $YT_2Si_2$  (T = Co, Ni, Cu, Ru, Rh, Pd) samples were yttrium ingots (smart elements), lumps of cobalt (Alfa Aesar), nickel wire (Alfa Aesar), copper shots (Alfa Aesar), ruthenium, rhodium and palladium powder (Allgussa AG) and lumps of silicon (Strem Chemicals), all with a stated purity better than 99.9 %. Powdered elements were cold-pressed to pellets ( $\emptyset$  6 mm).

The elements were weighed in the stoichiometric ratio and arc-melted [32] in a dried argon atmosphere of about 700 mbar. The argon was purified over titanium sponge (900 K), silica gel, and molecular sieves. All buttons were turned over and remelted several times to ensure good homogeneity. The weight losses after several meltings were in all cases smaller than 0.5 %. The crushed buttons had a light grey color with metallic luster. They are stable in air and no decomposition was visible after several months.

#### X-Ray diffraction

The polycrystalline  $YT_2Si_2$  samples were analyzed by X-ray powder diffraction using the Guinier technique (imaging plate detector, Fujifilm BAS-1800) with Cu $K_{\alpha 1}$ radiation and  $\alpha$ -quartz (a = 491.30 and c = 540.46 pm) as an internal standard. The tetragonal lattice parameters (Table 1) were deduced from least-squares fits. Our data are in agreement with literature values. Correct indexing was ensured through intensity calculations [33].

 $YT_2Si_2$  single crystals were selected from the crushed samples. The crystals were fixed at thin quartz fibers using beeswax and investigated by Laue photographs in a Buerger camera (white molybdenum radiation; imaging plate technique, Fujifilm, BAS-1800). Intensity data of an YNi<sub>2</sub>Si<sub>2</sub> crystal were collected at room temperature using a four-circle diffractometer (CAD4) with graphite monochromatized Mo $K_{\alpha}$  radiation and a scintillation counter with pulse height discrimination. Scans were taken in the  $\omega/2\theta$ mode. The YCo<sub>2</sub>Si<sub>2</sub>, YRu<sub>2</sub>Si<sub>2</sub> and YRh<sub>2</sub>Si<sub>2</sub> crystals were measured on a Stoe IPDS-II imaging plate diffractometer in oscillation mode (graphite-monochromatized Mo radiation). Numerical absorption corrections were applied to these four data sets. Data of the YPd<sub>2</sub>Si<sub>2</sub> crystal were measured on a Stoe StadiVari system equipped with a Mo microfocus source and a Pilatus 100 K detector with a hybrid-pixel-sensor. An empirical absorption correction was applied to this data set. Details about the data collections and the crystallographic parameters are summarized in Table 2.

#### Structure refinements

The systematic extinctions of the five data sets were in agreement with the centrosymmetric space group I4/mmm. The atomic positions of the aristotype ThCr<sub>2</sub>Si<sub>2</sub> [2] were taken as starting values and the structures were refined using the JANA2006 package [34, 35] with anisotropic atomic displacement parameters (ADPs) for all atoms. The occupancy parameters of all sites were refined in separate series of least squares cycles. All sites were fully occupied within two standard deviations. The final difference Fourier synthesis showed no significant residual peaks. The refined atomic positions, the ADPs, and the interatomic distances are given in Tables 3 and 4.

Further details of the structure refinement may be obtained from the Fachinformationszentrum Karlsruhe, D-76344 Eggenstein-Leopoldshafen (Germany), by quoting the Registry No's. CSD-427109 (YCo<sub>2</sub>Si<sub>2</sub>), CSD-427110 (YNi<sub>2</sub>Si<sub>2</sub>), CSD-427111 (YRu<sub>2</sub>Si<sub>2</sub>), CSD-427112 (YRh<sub>2</sub>Si<sub>2</sub>), and CSD-427113 (YPd<sub>2</sub>Si<sub>2</sub>).

#### <sup>89</sup>Y Solid state NMR spectroscopy

<sup>89</sup>Y solid state NMR spectra were measured on a Bruker DSX-500 spectrometer equipped with a 7 mm low-gamma magic-angle spinning MAS-NMR probe (<sup>89</sup>Y resonance frequency 24.5 MHz). To minimize probe detuning and rf sample heating effects of these metallic samples, intimate mixtures of the powdered material and αquartz in a 1:1 mass ratio were investigated. Samples were rotated at the magic angle with rotation speeds of 5-7 kHz, and spectra were obtained in the form of Bloch decay signals, using 90° pulses of 9.5 µs length, and relaxation delays of 2-5 seconds. To suppress probe ringing effects, all the spectra were obtained following a pre-acquisition delay of one rotor period. Resonance shifts are reported relative to an external 1M aqueous YCl<sub>3</sub> solution.

#### Computational details

Within the well-established quantum theoretical density functional theory (DFT) framework [36, 37] we used the generalized gradient approximation GGA [38] for an account of the effects of exchange-correlation. Based on DFT-GGA, calculations were carried out within the all electron scalar-relativistic augmented spherical wave (ASW) method [39, 40]. The method allows for a full description of the electronic structure and the properties of chemical bonding based on the analysis of the overlap integrals  $S_{ij}$  with the crystal orbital overlap populations COOP following Hoffmann [41]. In the plots, positive, negative, and zero COOP indicate bonding, anti-bonding, and non-bonding interactions, respectively. Due to the limited basis set used in the ASW method, we chose the outermost shells to represent the valence states and the matrix elements were constructed using partial waves up to  $l_{max} + 1 = 4$  for Y,  $l_{max} + 1 = 3$  for T and  $l_{max} + 1 = 2$  for Si. Self-consistency was achieved when charge transfers and energy changes between two successive cycles were below  $10^{-8}$  and  $10^{-6}$  eV, respectively. BZ integrations were performed using the linear tetrahedron method within the irreducible wedge.

#### **Results and Discussion**

#### Crystal chemistry

The crystal chemistry and chemical bonding of the various phases derived from the ThCr<sub>2</sub>Si<sub>2</sub> structure has been summarized repeatedly [4, 5, 9-11, 42]. Herein we only focus on the details that are relevant for the yttrium-based silicides. The transition metal atoms have tetrahedral silicon coordination with T-Si distances close to the sums of the covalent radii [43]. Layers of edge-sharing TSi<sub>4/4</sub> tetrahedra (Fig. 1) are connected via Si-Si bonding. The Si-Si distances range from 233 pm in YCu<sub>2</sub>Si<sub>2</sub> to 251 pm in  $YRu_2Si_2$ , typical for single bonds. The three-dimensional  $[T_2Si_2]$  polyanionic networks leave larger cages which are filled by the yttrium atoms. Besides strong covalent T-Si and Si–Si bonding, there is evidence for weak T–T bonding [11]. The local environment of the yttrium atoms is characterized by two interpenetrating polygons with eight identical Y–Si and eight identical Y–T distances, where the ratio of these distances is reflected by the c/a lattice parameter ratio. Fig. 2 shows the dependence of cell volume on the transition metal, including all  $YT_2Si_2$  compounds listed in the Pearson data base [3]. Similar to the family of  $ThT_2Si_2$  silicides already reported in 1965 [3], the  $YT_2Si_2$ series shows distinct minima in the cell volumina for the Co, Rh, and Ir compounds, suggesting maximum bond strength in the compounds formed by T atoms of group IX. The c/a ratios (YCo<sub>2</sub>Si<sub>2</sub>: 2.504; YNi<sub>2</sub>Si<sub>2</sub>: 2.419; YCu<sub>2</sub>Si<sub>2</sub>: 2.514; YRu<sub>2</sub>Si<sub>2</sub>: 2.296; YRh<sub>2</sub>Si<sub>2</sub>: 2.463; YPd<sub>2</sub>Si<sub>2</sub>: 2.388) show the by far smallest value for YRu<sub>2</sub>Si<sub>2</sub>. This results in anomalously long Y-Si distances (320 pm), which are in this case even longer than the Y-Ru distances (317 pm). This reversal in the order of the closest nearest neighbors in YRu<sub>2</sub>Si<sub>2</sub> as compared to all the other members in this series influences the bonding situation of the yttrium atoms, as discussed below on the basis of <sup>89</sup>Y solid state NMR spectra and overlap populations.

#### Electronic structure calculations for YRu<sub>2</sub>Si<sub>2</sub> and YRh<sub>2</sub>Si<sub>2</sub>

Calculations assume spin degenerate (total spins) configuration, *i. e.* no spin polarization (NSP). At self-consistent convergence little charge transfer could be observed between the atomic species as it is the case of an intermetallic compound, the major effect being the quantum mixing between the valence states of the constituents within the valence band (VB). This is illustrated by the site projected density of states

(PDOS) given in Fig. 3 for the two compounds as a function of the energy difference  $E_ E_F$ , where  $E_F$  is the Fermi energy. The two panels show similar features pertaining to Si (s, p) states low in energy,  $-12 \le (E-E_F) \le -8$  eV, as well as for the low-energy part of the *T* (*d*) states. These features indicate the expected strong *T*–Si bonding interactions within the  $T_2Si_2$  layers characterizing the structure. A major feature differentiating the two compounds which exhibit nearly similar DOS is in the Fermi level upshift in YRh<sub>2</sub>Si<sub>2</sub> due to the extra electron brought in by Rh. This leads to twice larger Ru(PDOS) *vs*. Rh(PDOS). However, no subsequent magnetic instability of the Rh compound could be traced out through spin polarized (SP) calculations.

Fig. 4 shows the crystal orbital overlap populations (COOP) for the pair interactions accounting for the site multiplicities. As in Fig. 3 the energy is plotted relative to the Fermi level  $E_{\rm F}$ . Major bonding is, as expected from the above discussion, within the  $T_2 {\rm Si}_2$  layers. It is of a bonding nature (positive COOP magnitudes along the *y* axis) and starts to exhibit small antibonding contributions near  $E_{\rm F}$  in the Rh compound. This follows from the Fermi level upshift in YRh<sub>2</sub>Si<sub>2</sub>. Also the Y–T bonding is of small magnitude and is not significantly different between the two compounds. However a major difference going beyond the Fermi level upshift is shown by the large Y–Si bonding COOP in YRh<sub>2</sub>Si<sub>2</sub>. This follows the course of the Y–Si distances: 309 pm in YRh<sub>2</sub>Si<sub>2</sub> *vs.* 320 pm in YRu<sub>2</sub>Si<sub>2</sub>.

Thus, while the electronic structures of YRu<sub>2</sub>Si<sub>2</sub> and YRh<sub>2</sub>Si<sub>2</sub> reveal similarities regarding their DOS shapes, the effect of the extra electron contributed by the Rh atoms is clearly evident.

#### <sup>89</sup>Y Solid state NMR spectroscopy

Fig. 5 and Table 5 summarize the solid state NMR results. As expected, the spectra reveal single crystallographic yttrium sites, whose resonance shifts are highly dependent on the *T* atom present. Within both series of compounds involving *T* atoms of the  $4^{\text{th}}$  and  $5^{\text{th}}$  period, respectively, the Knight shift decreases systematically with increasing valence electron count. In addition, unsystematic variations in the line widths (full width at half maximum) are observed, which we attribute to variations in the extent of structural and electronic disorder realized by the synthetic procedure used. The particularly anomalous behavior shown by YRu<sub>2</sub>Si<sub>2</sub> regarding its crystal chemistry is

also seen in the <sup>89</sup>Y NMR data. This compound not only shows the highest Knight shift within the entire series, but also indicates a strong Knight-shift anisotropy, as reflected by the strong spinning sideband intensities observed at integer multiples of the MAS rotation frequency. From an analysis of the peak intensity profile, the anisotropy parameters are estimated as  $\delta = -650$  ppm and  $\eta = 0.5$ . None of the other compounds measured here give any indication of a Knight shift anisotropy. A similar phenomenon was recently observed in a <sup>89</sup>Y NMR study of YTX compounds. While in YIrSn and in all YNiX (X = Si, Ge, Sn) compounds, the closest neighbors to yttrium are the transition metal atoms, an inverse situation is observed for YIrSi and YIrGe, where the Y–X distances are closer than the Y–Ir distances. Significantly, only the latter two compounds reveal significant Knight shift anisotropies [44]. Thus, we may conclude that this particular NMR parameter may be particularly sensitive to such site occupancy reversals.

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Compound	<i>a</i> (pm)	<i>c</i> (pm)	$V(nm^3)$	Reference
YCo <sub>2</sub> Si <sub>2</sub>	388.75(7)	973.4(3)	0.1471	this work
	396	978	0.1534	[27]
	389.2	975.9	0.1478	[23]
	389.04(6)	975.1(2)	0.1476	[26]
YNi <sub>2</sub> Si <sub>2</sub>	395.51(7)	956.8(2)	0.1497	this work
	395	953	0.1487	[30]
	395.6	953.5	0.1492	[24]
	396.4	959.9	0.1508	[25]
YCu <sub>2</sub> Si <sub>2</sub>	396.15(7)	995.9(2)	0.1563	this work
	396.7	995.9	0.1567	[24]
	396.75(7)	997.6(3)	0.1570	[20]
	396.7	995.9	0.1567	[21]
	397.06(2)	998.07(7)	0.1574	[27, 28]
$YRu_2Si_2$	415.80(6)	954.6(2)	0.1650	this work
	415.57(6)	953.7(3)	0.1647	[22]
	415.7(1)	952.2(3)	0.1645	[12]
$YRh_2Si_2$	401.81(9)	989.7(3)	0.1598	this work
	403.1	992	0.1612	[31]
	403.1(2)	992(1)	0.1612	[19]
	402.3(1)	990.0(6)	0.1602	[12]
	403.1	992.0	0.1612	[14]
$YPd_2Si_2$	412.77(3)	985.74(9)	0.1679	this work
	412.2	992	0.1685	[31]
	412.5(1)	984.2(4)	0.1675	[12]
	412.9	984	0.1678	[14]

Table 1. Refined lattice parameters (Guinier powder data) of the silidcides  $YT_2Si_2$  (T = Co, Ni, Cu, Ru, Rh, Pd) with ThCr<sub>2</sub>Si<sub>2</sub> type structure.

Z=2.					
Empirical formula	YCo <sub>2</sub> Si <sub>2</sub>	YNi <sub>2</sub> Si <sub>2</sub>	$YRu_2Si_2$	$YRh_2Si_2$	$YPd_2Si_2$
Molar mass, g $mol^{-1}$	262.9	262.5	347.2	350.9	357.9
Unit cell dimensions					
(Guinier powder data)					
<i>a</i> , pm	388.75(7)	395.51(7)	415.80(6)	401.81(9)	412.77(3)
<i>c</i> , pm	973.4(3)	956.8(2)	954.6(2)	989.7(3)	985.74(9)
Cell volume, nm <sup>3</sup>	0.1471	0.1497	0.1650	0.1598	0.1679
Calculated density, g cm <sup>-3</sup>	5.93	5.82	6.99	7.29	7.07
Crystal size, $\mu m^3$	$10\times15\times20$	$20\times 20\times 100$	$15\times 20\times 40$	$10\times15\times30$	$10\times10\times20$
Transm. ratio (max / min)	0.67 / 0.30	0.49 / 0.26	0.41 / 0.25	0.18 / 0.12	0.22 / 0.13
Diffractometer	IPDS II	CAD4	IPDS II	IPDS II	StadiVari
Detector distance, mm	60	-	60	60	60
Exposure time, sec	600	-	360	600	50
$\omega$ range; increment, deg	0-180; 1.0	-	0-180; 1.0	0-180; 1.0	_
Integr. parameters A, B, EMS	13.2, 2.9, 0.012	_	12.7, 2.8, 0.011	12.9, 2.9, 0.013	8.6, -8.0, 0.03
Absorption coefficient, mm <sup>-1</sup>	31.2	32.2	26.9	28.7	28.2
<i>F</i> (000), e	242	246	310	314	318
$\theta$ range, deg	4.2° - 34.8°	4.3 - 49.8	4.3 - 34.7	4.1 - 34.9	5.4-40.0
Range in hkl	±6, ±6, +15	±8, ±8, +20	±6, ±6, +15	±6, ±6, +15	±7, ±7, ±17
Total no. reflections	633	1538	691	685	3046
Independent reflections / R <sub>int</sub>	122 / 0.0467	264 / 0.0253	131 / 0.0208	131 / 0.0164	186 / 0.0451
Reflections with $I \ge 3 \sigma(I)$	101 / 0.0250	247 / 0.0128	128 / 0.0101	128 / 0.0140	157 / 0.0257
Data / parameters	122 / 9	264 / 9	131/9	131/9	186/9
Goodness-of-fit on $F^2$	1.57	1.68	0.73	1.26	1.55
$R1 / wR2$ for $I \ge 3 \sigma(I)$	0.0274 / 0.0556	0.0176 / 0.0562	0.0088 / 0.0197	0.0138 / 0.0374	0.0281 / 0.0639
R1/wR2 for all data	0.0356 / 0.0569	0.0194 / 0.0565	0.0093 / 0.0198	0.0146 / 0.0375	0.0337 / 0.0654
Extinction coefficient	160(30)	100(20)	119(7)	128(12)	83(18)
Largest diff. peak / hole, e A <sup>-3</sup>	2.44 / -1.21	1.92 / -1.09	0.32 / -0.26	0.81 / -0.66	1.64 / -1.78

Table 2. Crystal data and structure refinement for  $YT_2Si_2$  (T = Co, Ni, Ru, Rh, Pd) with ThCr<sub>2</sub>Si<sub>2</sub> structure type, space group *I4/mmm*, Z = 2.

						0		
Atom	site	x	у	Z	$U_{11}$	$U_{33}$	$U_{ m eq}$	
YCo <sub>2</sub> Si <sub>2</sub>								
Y	2a	0	0	0	49(4)	61(5)	53(3)	
Co	4d	0	1/2	1/4	47(4)	53(5)	49(2)	
Si	4e	0	0	0.3731(3)	45(6)	55(9)	48(4)	
YNi <sub>2</sub> Si <sub>2</sub>								
Y	2a	0	0	0	41(1)	60(2)	47(1)	
Ni	4d	0	1/2	1/4	76(1)	65(2)	72(1)	
Si	4e	0	0	0.3742(1)	59(2)	74(4)	64(2)	
YCu <sub>2</sub> Si <sub>2</sub> [27]								
Y	2a	0	0	0	_	_	_	
Cu	4d	0	1/2	1/4	_	_	_	
Si	4e	0	0	0.38314(18)	_	_	_	
YRu <sub>2</sub> Si <sub>2</sub>	2							
Y	2a	0	0	0	58(1)	59(2)	58(1)	
Ru	4d	0	1/2	1/4	28(1)	47(1)	34(1)	
Si	4e	0	0	0.36837(9)	43(2)	52(3)	46(2)	
YRh <sub>2</sub> Si <sub>2</sub>	2							
Y	2a	0	0	0	71(3)	76(3)	73(2)	
Rh	4d	0	1/2	1/4	51(2)	72(2)	58(1)	
Si	4e	0	0	0.3777(2)	67(5)	78(7)	71(3)	
YPd <sub>2</sub> Si <sub>2</sub>								
Y	2a	0	0	0	149(4)	145(6)	148(3)	
Pd	4d	0	1/2	1/4	154(2)	157(3)	155(1)	
Si	4 <i>e</i>	0	0	0.3827(3)	157(8)	167(13)	160(6)	

Table 3. Atomic positions and anisotropic displacement parameters (pm<sup>2</sup>) of  $YT_2Si_2$  (T = Co, Ni, Cu, Ru, Rh, Pd), space group *I4/mmm*. The anisotropic displacement factor exponent takes the form:  $-2\pi^2[(ha^*)^2U_{11}+...+2hka^*b^*U_{12}]$ ;  $U_{11} = U_{22}$ ;  $U_{12} = U_{13} = U_{13} = 0$ ;  $U_{eq}$  is defined as one third of the trace of the orthogonalized  $U_{ij}$  tensor.

Table 4. Interatomic distances (pm) in the structures of  $YT_2Si_2$  (T = Co, Ni, Cu, Ru, Rh, Pd). Standard deviations are all equal or less than 0.3 pm. All distances within the first coordination spheres are listed. The data of the copper compound were taken from [27].

		YCo <sub>2</sub> Si <sub>2</sub>	YNi <sub>2</sub> Si <sub>2</sub>	YCu <sub>2</sub> Si <sub>2</sub>	YRu <sub>2</sub> Si <sub>2</sub>	YRh <sub>2</sub> Si <sub>2</sub>	YPd <sub>2</sub> Si <sub>2</sub>
Y 8	Si	301.4	304.5	304.0	319.7	308.8	313.9
8	Т	311.4	310.4	318.9	316.5	318.7	321.4
T 4	Si	228.3	230.7	238.9	236.6	237.4	244.3
4	Т	274.9	279.7	280.8	294.0	284.1	291.9
4	Y	311.4	310.4	318.9	316.5	318.7	321.4
Si 4	Т	228.3	230.7	238.9	236.6	237.4	231.3
1	Si	247.1	240.8	233.3	251.3	242.0	244.3
4	Y	301.4	304.5	304.0	319.7	308.8	313.9

$01 11_2 S1_2 (1 - C0, INI, Cu, Ku, KII, Fu).$					
Compound	$\delta_{iso}$ (ppm)	$\Delta$ (Hz)			
YCo <sub>2</sub> Si <sub>2</sub>	1521	825			
$YNi_2Si_2$	832	2634			
YCu <sub>2</sub> Si <sub>2</sub>	585	292			
$YRu_2Si_2$	2131	682			
$YRh_2Si_2$	1278	481			
$YPd_2Si_2$	1013	537			

Table 5. <sup>89</sup>Y MAS NMR fitting parameters of  $YT_2Si_2$  (T = Co, Ni, Cu, Ru, Rh, Pd).

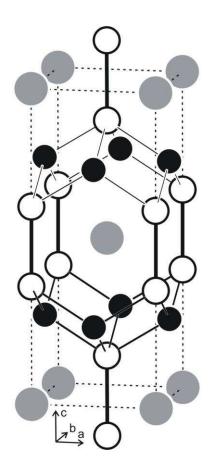


Fig. 1. The crystal structure of the silicides  $YT_2Si_2$ . Yttrium, transition metal, and silicon atoms are drawn as medium grey, black filled and open circles, respectively. The three-dimensional  $[T_2Si_2]$  network is emphasized.

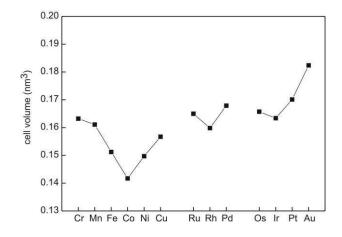


Fig. 2. Course of the cell volumes of the silicides  $YT_2Si_2$  as a function of the atomic number of the transition metal. Data that are not listed in Table 1 were taken from the Pearson data base [3].

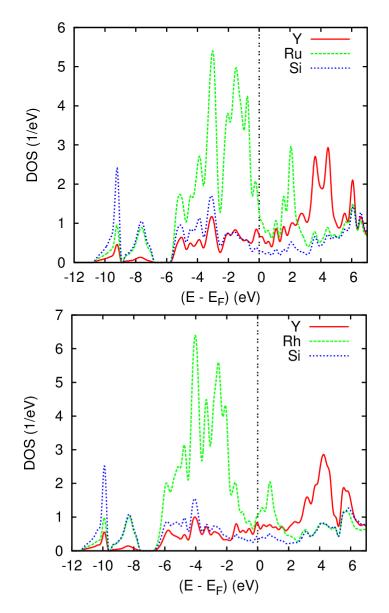


Fig. 3 (color online). Electronic density of states DOS. Site projected DOS (PDOS) of  $YRu_2Si_2$  (top) and  $YRh_2Si_2$  (bottom).

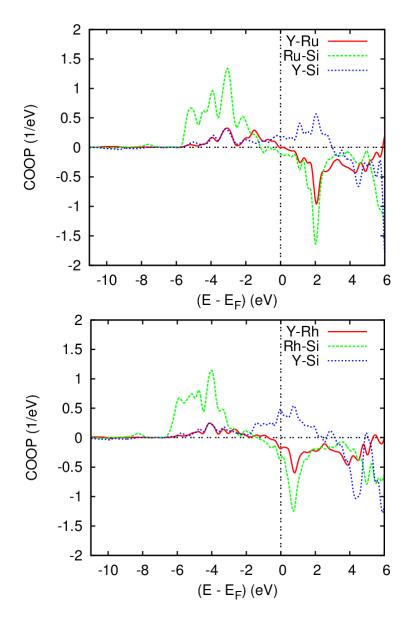


Fig. 4 (color online). Chemical bonding from overlap populations with the COOP criterion for the different interactions in  $YRu_2Si_2$  (top) and  $YRh_2Si_2$  (bottom).

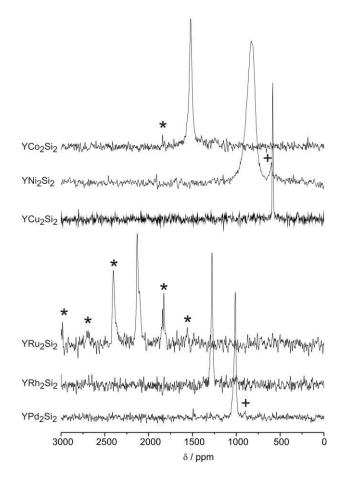


Fig. 5. 24.5 MHz solid state NMR spectra of the series of  $YT_2Si_2$  (T = Co, Ni, Cu, Ru, Rh, Pd) silicides at room temperature (from top to bottom). Impurities and spinning sidebands are marked by crosses and asterisks, respectively.